SOUTH AFRICAN CONFERENCE ON SEMI- AND SUPERCONDUCTOR TECHNOLOGY 2009

Spier Wine Estate, Stellenbosch 8 – 9 April 2009



Programme

Tuesday 7 April 2000	
Tuesday, 7 April 2009 Neethlingshof Wine Estate	
9:00 IEEE's 125th anniversary celebration	
Hosted by Prof Monuko du Plessis and Dr Saurabh Sinha	
Inosted by Prof Worldko du Piessis and Di Sadrabit Sinita	
Wednesday, 8 April 2009	
Spier Wine Estate	
08:00 Registration, tea and coffee	
09:00 Opening, welcome and house rules	
Prof Willem Perold (Univ Stellenbosch) - Conference Chair	
Dr Thandi Mqwebi (NRF) - Programme Director: Human Capacity Programme	
Prof Robert van Zyl (CPUT) - Programnme Chair	Plenaries
09:20 A South African Perspective	
Prof Monuko du Plessis (semiconductor technology)	
Prof Willem Perold (superconductor technology)	Chair: Robert van Zyl
09:40 [35] The growth mechanism and photonic properties of 1D and 2D ZnO nanostructures by low temperature method - Sithole MJ	Í
[38] The capability at Stellenbosch University for the fabrication of micron and submicron structures - Buttner U	
[22] A SONET OC-48 CMOS based integrated optical transceiver - Kalombo TY	Session 1: Posters in the
[03] Effects of grain size on mechanical properties of nanostructured copper alloy by Severe Plastic Deformation (SPD) Process - Sanusi K	foyer
[11] 3D CMOS Photodiode modelling and simulator design using the Finite Element Method - Ellinghaus P	
16 Electrochromic and photochromic behaviour of electrospun WO3 nanofibres deposited on TCÖ substrates - Sone BT	Chair: Prof Robert van Zvl
10:40l Tea	,
11:00 19 A CMOS based multiple-access DSSS transceiver - Sinha S	
11:20 [12] Impact of future CMOS scaling on power consumption: Flectrical versus optical clock distribution networks - Venter P.I.	
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11:40 [2] Design methodology for SiGe-based Class E power amplifier - Božanić M	Session 2: HF Microelectronics
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	Thursday, 9 April 2009	
	Spier Wine Estate	
08:00	Tea, coffee	
08:30	Plenary Session: Prof Cor Claeys	Plenary
	Trends and Challenges in More Moore and More than Moore Research	Chair: Prof Monuko du Plessis
09:30	Short break	
09:40	[1] A 384x288 pixel CMOS image readout chip - Joubert T	
10:00	[30] A CMOS implementation of Jakes Fading Channel - Buckle JP	Sanaian E. IC Simulation
10:20	[36] High speed, low power CMOS optical receiver front-end - Janse van Rensburg C	Session 5: IC Simulation,
	[26] Expanded adaptive LMS algorithm for the removal of interference in capacitive sensing devices - van der Merwe SJ	Layout
	[21] Mathematical analysis of input matching techniques for application in wide-band LNA design - Weststrate M	
11:20	[28] Development of a next-generation commercial computer aided design (CAD) tool - Pool J	Chair: Prof Lukas Snyman
11:40	Tea	
12:00	[09] Design and manufacture of nanometre-scale SOI light sources - Bogalecki AW	
	[39] Photonic transitions (1.4eV-2.8eV) in Silicon p+np+ injection-avalanche CMOS LEDs as function of depletion layer profiling and defect engineering - Snyman LW	Session 6: Photonics /
12:20		Optics / Physics
	[40] Simulation of Si LED (450nm - 750nm) light propagation phenomena in CMOS integrated circuitry for MOEMS applications - Snyman LW	Optics / Physics
	[15] MOVPE growth and characterisation of III-V Sb-based quantum well structures - Wagener V	
	[27] Hall and thermoelectric evaluation of narrow gap semiconductors - Wagener MC	Chair: Dr Saurabh Sinha
13:40	Lunch / prizegiving / Closing - Prof Monuko du Plessis	











